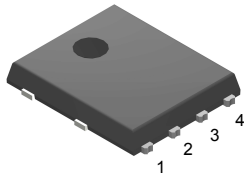
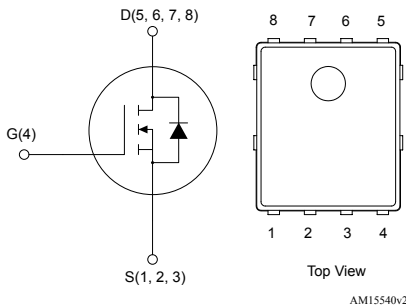



Automotive-grade N-channel 30 V, 4 mΩ typ., 80 A STripFET™ H6 Power MOSFET in a PowerFLAT™ 5x6 package


PowerFLAT™ 5x6


Features

Order code	V _{DS}	R _{DS(on)} max.	I _D
STL86N3LLH6AG	30 V	5.2 mΩ	80 A

- AEC-Q101 qualified 
- Very low on-resistance
- Very low gate charge
- High avalanche ruggedness
- Low gate drive power loss
- Logic level
- Wettable flank package

Applications

- Switching applications

Description

This device is an N-channel Power MOSFET developed using the STripFET™ H6 technology with a new trench gate structure. The resulting Power MOSFET exhibits very low R_{DS(on)} in all packages.

Product status link

[STL86N3LLH6AG](#)

Product summary

Order code	STL86N3LLH6AG
Marking	86N3LLH6
Package	PowerFLAT™ 5x6
Packing	Tape and reel

1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage	30	V
V_{GS}	Gate-source voltage	± 20	V
$I_D^{(1)}$	Drain current (continuous) at $T_C = 25\text{ }^\circ\text{C}$	80	A
$I_D^{(1)}$	Drain current (continuous) at $T_C = 70\text{ }^\circ\text{C}$	60	A
$I_D^{(1)}$	Drain current (continuous) at $T_C = 100\text{ }^\circ\text{C}$	51	A
$I_{DM}^{(2)(1)}$	Drain current (pulsed)	320	A
$I_D^{(3)}$	Drain current (continuous) at $T_{pcb} = 25\text{ }^\circ\text{C}$	21	A
$I_D^{(3)}$	Drain current (continuous) at $T_{pcb} = 70\text{ }^\circ\text{C}$	15.7	A
$I_D^{(3)}$	Drain current (continuous) at $T_{pcb} = 100\text{ }^\circ\text{C}$	13.1	A
$I_{DM}^{(2)(3)}$	Drain current (pulsed)	84	A
$P_{TOT}^{(1)}$	Total power dissipation at $T_C = 25\text{ }^\circ\text{C}$	60	W
$P_{TOT}^{(3)}$	Total power dissipation at $T_{pcb} = 25\text{ }^\circ\text{C}$	4	
T_{stg}	Storage temperature range	- 55 to 150	$^\circ\text{C}$
T_j	Operating junction temperature range		

1. The value is rated according to R_{thj-c} .
2. Pulse width limited by safe operating area.
3. The value is rated according to $R_{thj-pcb}$.

Table 2. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case	2.08	$^\circ\text{C/W}$
$R_{thj-pcb}^{(1)}$	Thermal resistance junction-pcb	31.3	

1. When mounted on FR-4 board of 1 inch², 2oz Cu, $t < 10\text{ s}$

2 Electrical characteristics

($T_C = 25\text{ °C}$ unless otherwise specified).

Table 3. On/off-states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0\text{ V}$, $I_D = 1\text{ mA}$	30			V
I_{DSS}	Zero gate voltage drain current	$V_{GS} = 0\text{ V}$, $V_{DS} = 30\text{ V}$			1	μA
		$V_{GS} = 0\text{ V}$, $V_{DS} = 30\text{ V}$, $T_C = 125\text{ °C}^{(1)}$			10	
I_{GSS}	Gate-body leakage current	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$			± 100	nA
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$	1	1.7	2.5	V
$R_{DS(on)}$	Static drain-source on-resistance	$V_{GS} = 10\text{ V}$, $I_D = 10.5\text{ A}$		4	5.2	$\text{m}\Omega$
		$V_{GS} = 4.5\text{ V}$, $I_D = 10.5\text{ A}$		6.7	7.6	$\text{m}\Omega$

1. Defined by design, not subject to production test.

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{iss}	Input capacitance	$V_{DS} = 25\text{ V}$, $f = 1\text{ MHz}$, $V_{GS} = 0\text{ V}$	1350	1690	2030	pF
C_{oss}	Output capacitance		230	290	350	pF
C_{rSS}	Reverse transfer capacitance		140	176	210	pF
Q_g	Total gate charge	$V_{DD} = 15\text{ V}$, $I_D = 21\text{ A}$,	-	17	-	nC
Q_{gs}	Gate-source charge	$V_{GS} = 0\text{ to }4.5\text{ V}$	-	8	-	nC
Q_{gd}	Gate-drain charge	(see Figure 12. Test circuit for resistive load switching times)	-	6	-	nC
R_G	Gate input resistance	$f = 1\text{ MHz}$, $I_D = 0\text{ A}$	1.25	1.7	1.2	Ω

Table 5. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 15\text{ V}$, $I_D = 10.5\text{ A}$, $R_G = 4.7\text{ }\Omega$, $V_{GS} = 10\text{ V}$	-	9.5	-	ns
t_r	Rise time		-	30	-	ns
$t_{d(off)}$	Turn-off delay time	See Figure 12. Test circuit for resistive load switching times and Figure 17. Switching time waveform	-	37	-	ns
t_f	Fall time		-	12	-	ns

Table 6. Source-drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD}	Source-drain current		-		21	A
$I_{SDM}^{(1)}$	Source-drain current (pulsed)		-		84	A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD} = 21\text{ A}$, $V_{GS} = 0\text{ V}$	-		1.1	V
t_{rr}	Reverse recovery time	$I_{SD} = 10.5\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$	-	24		ns
Q_{rr}	Reverse recovery charge	$V_{DD} = 25\text{ V}$	-	16.8		nC
I_{RRM}	Reverse recovery current	See Figure 14. Test circuit for inductive load switching and diode recovery times	-	1.4		A

1. Pulse width limited by safe operating area.

2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%.

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

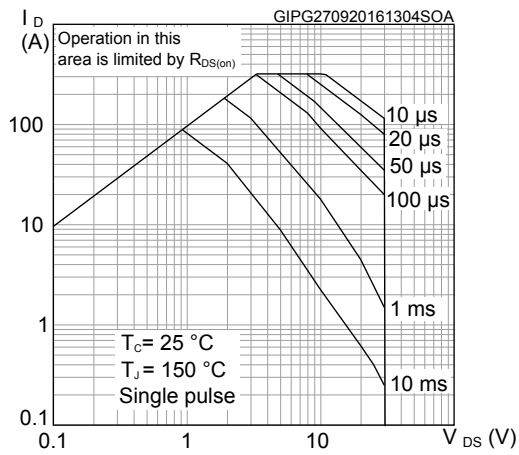


Figure 2. Thermal impedance

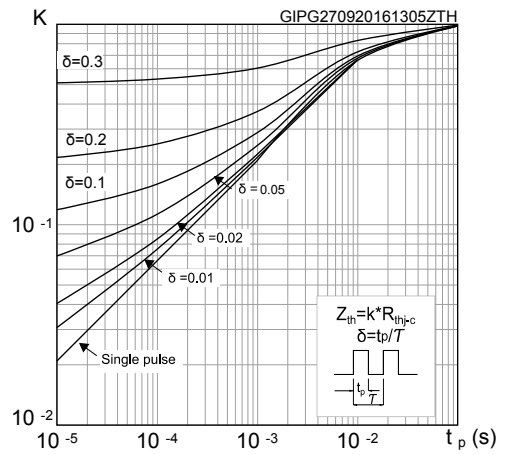


Figure 3. Output characteristics

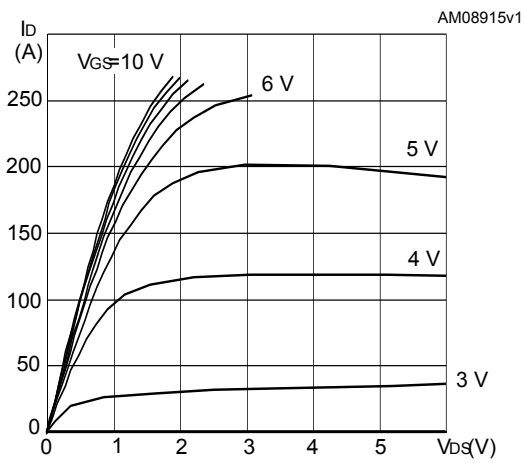


Figure 4. Transfer characteristics

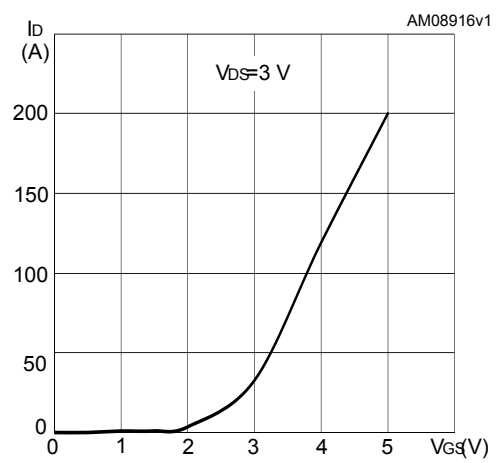


Figure 5. Normalized $V_{(BR)DSS}$ vs temperature

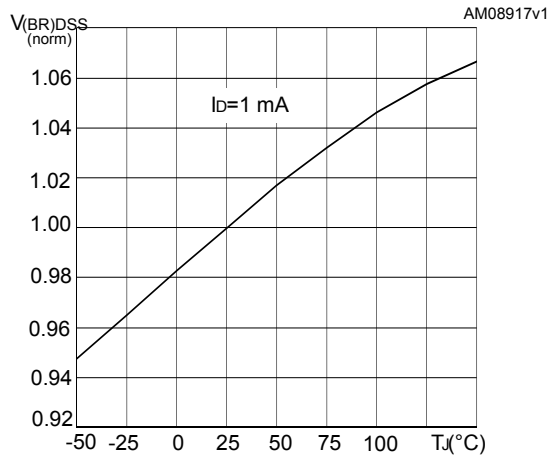


Figure 6. Static drain-source on-resistance

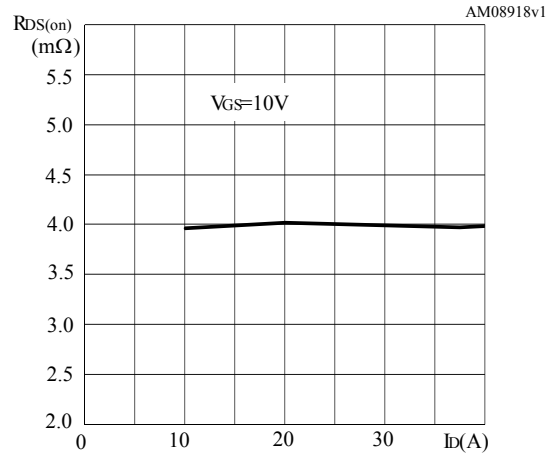


Figure 7. Gate charge vs gate-source voltage

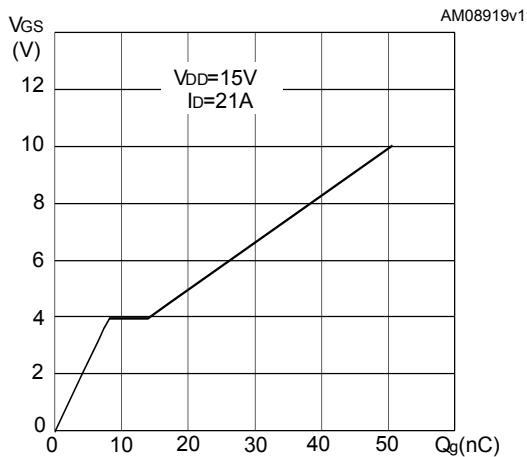


Figure 8. Capacitance variations

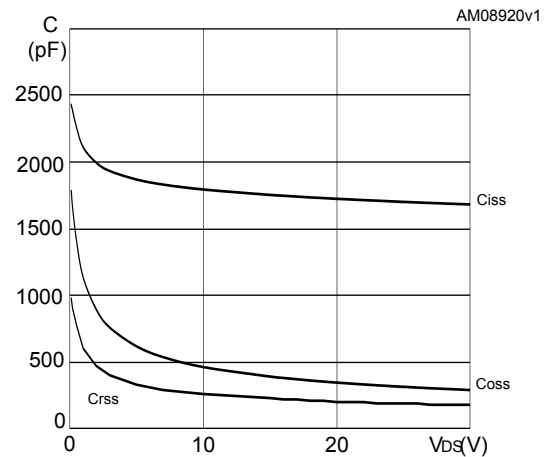


Figure 9. Normalized gate threshold voltage vs temperature

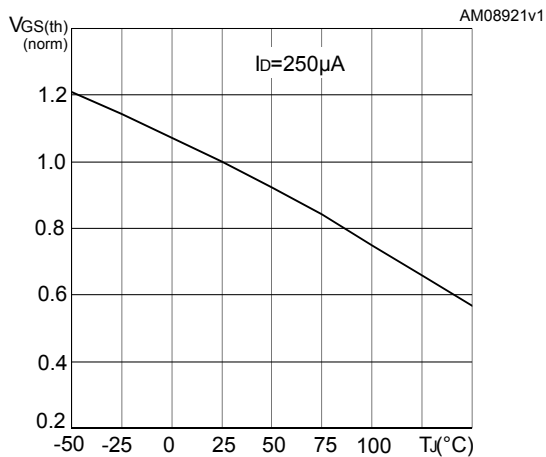


Figure 10. Normalized on resistance vs temperature

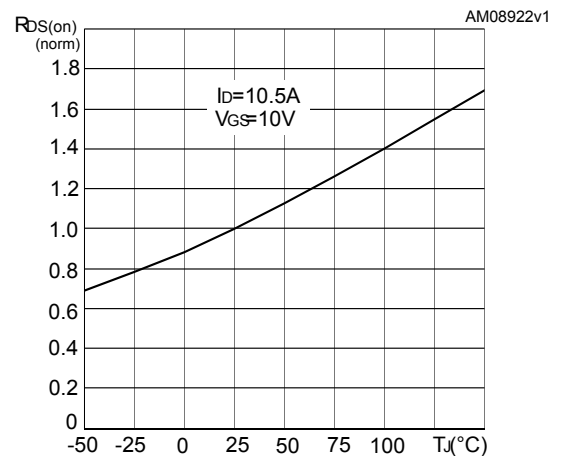
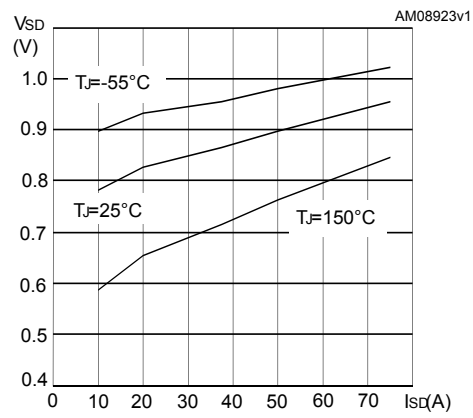
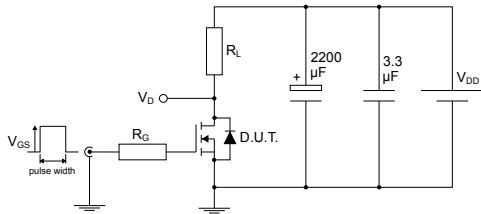


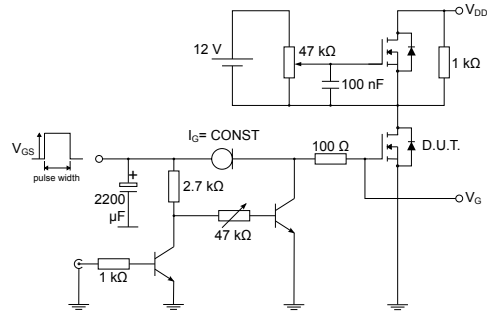
Figure 11. Source-drain diode forward characteristics



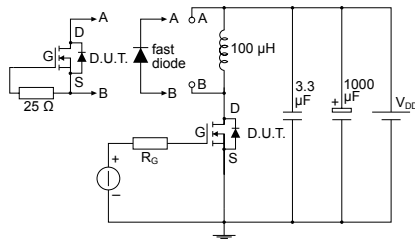
3 Test circuit

Figure 12. Test circuit for resistive load switching times


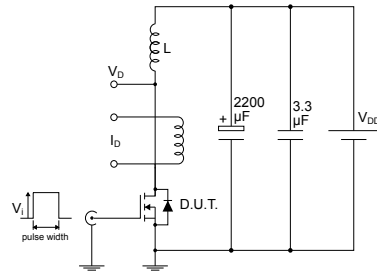
AM01468v1

Figure 13. Test circuit for gate charge behavior


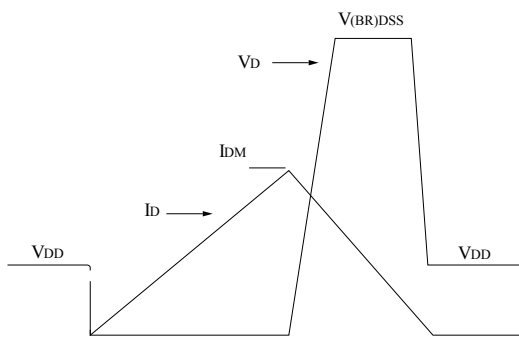
AM01469v1

Figure 14. Test circuit for inductive load switching and diode recovery times


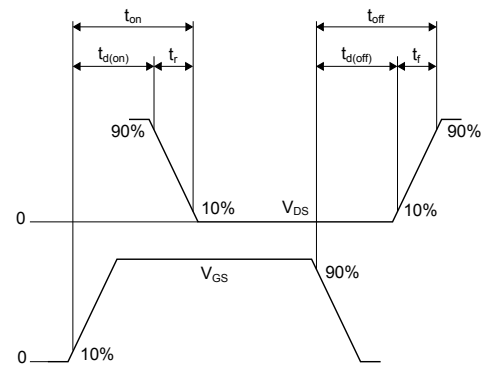
AM01470v1

Figure 15. Unclamped inductive load test circuit


AM01471v1

Figure 16. Unclamped inductive waveform


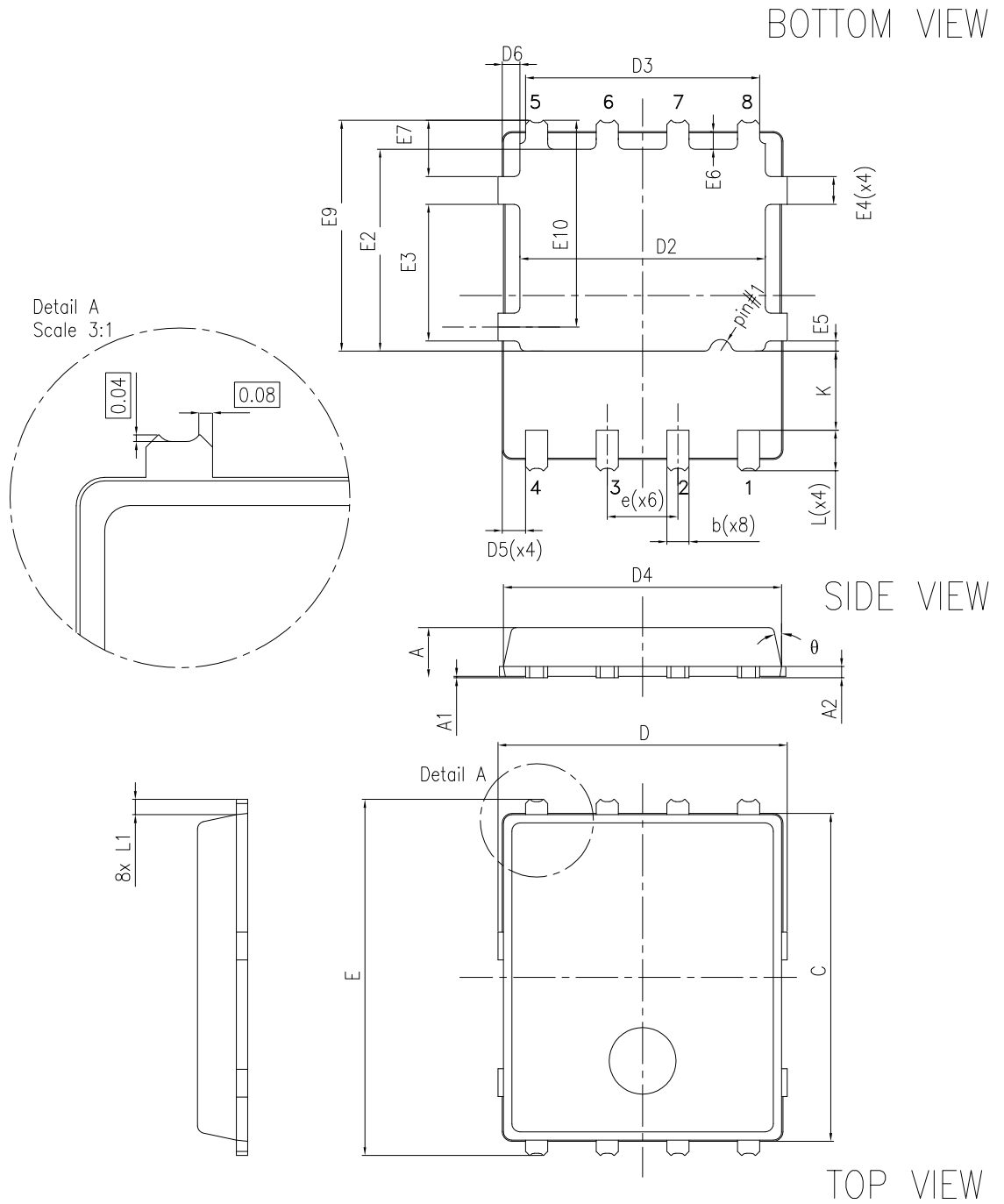
AM01472v1

Figure 17. Switching time waveform


AM01473v1

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK®** packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

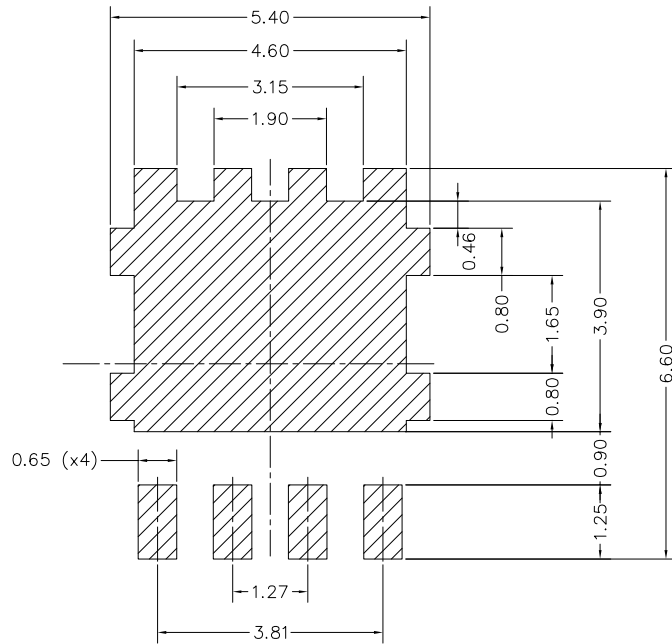
4.1 PowerFLAT™ 5x6 WF type R package information
Figure 18. PowerFLAT™ 5x6 WF type R package outline


8231817_R_WF_Rev_18

Table 7. PowerFLAT™ 5x6 WF type R mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	0.80		1.00
A1	0.02		0.05
A2		0.25	
b	0.30		0.50
C	5.80	6.00	6.10
D	5.00	5.20	5.40
D2	4.15		4.45
D3	4.05	4.20	4.35
D4	4.80	5.00	5.10
D5	0.25	0.4	0.55
D6	0.15	0.3	0.45
e		1.27	
E	6.20	6.40	6.60
E2	3.50		3.70
E3	2.35		2.55
E4	0.40		0.60
E5	0.08		0.28
E6	0.20	0.325	0.45
E7	0.85	1.00	1.15
E9	4.00	4.20	4.40
E10	3.55	3.70	3.85
K	1.275		1.575
L	0.725	0.825	0.925
L1	0.175	0.275	0.375
θ	0°		12°

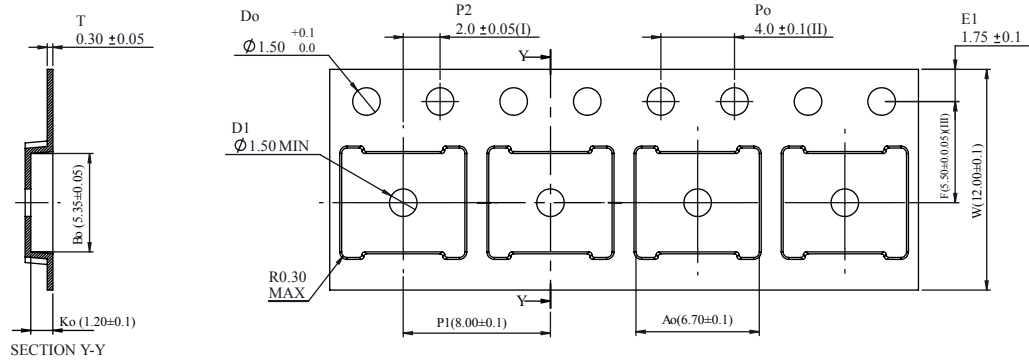
Figure 19. PowerFLAT™ 5x6 recommended footprint (dimensions are in mm)



8231817_FOOTPRINT_rev18

4.2 PowerFLAT™ 5x6 WF packing information

Figure 20. PowerFLAT™ 5x6 WF tape (dimensions are in mm)



- (I) Measured from centreline of sprocket hole to centreline of pocket.
- (II) Cumulative tolerance of 10 sprocket holes is ± 0.20 .
- (III) Measured from centreline of sprocket hole to centreline of pocket.

Base and bulk quantity 3000 pcs

8234350_TapeWF_rev_C

Figure 21. PowerFLAT™ 5x6 package orientation in carrier tape

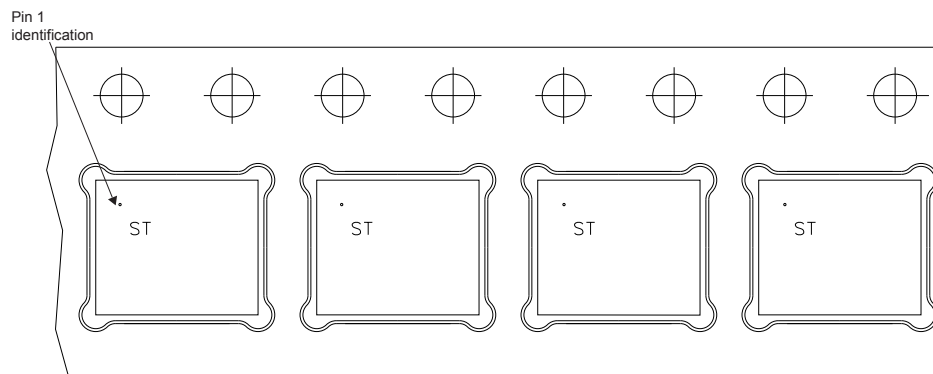
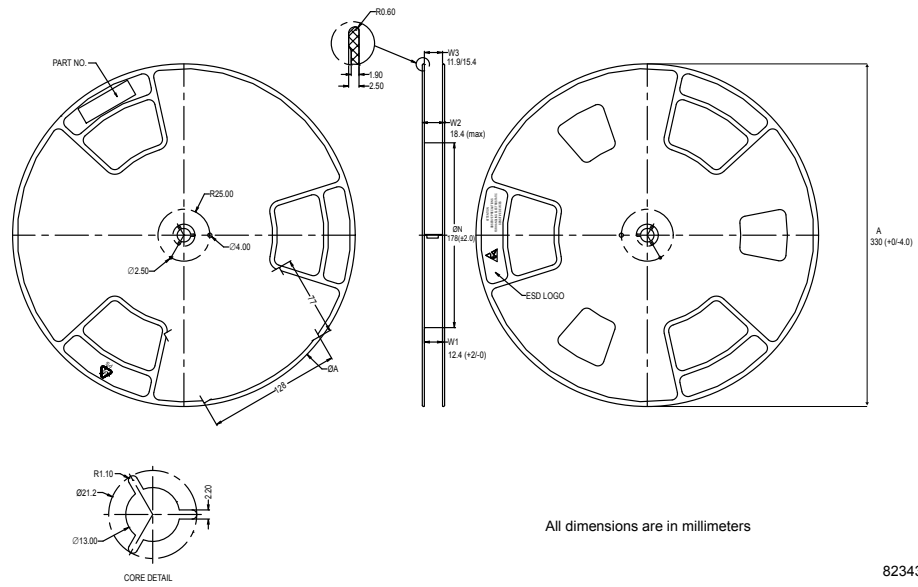


Figure 22. PowerFLAT™ 5x6 reel (dimensions are in mm)



Revision history

Table 8. Document revision history

Date	Revision	Changes
26-Sep-2014	1	First release.
21-Jan-2015	2	Document status promoted from preliminary to production data. Updated <i>Section 4: Package mechanical data</i> .
03-Feb-2015	3	Updated title and features in cover page.
03-Oct-2016	4	Updated title and features in cover page. Updated <i>Table 1. Absolute maximum ratings</i> and <i>Table 3. On/off-states</i> . Changed <i>Figure 1. Safe operating area</i> and <i>Figure 2. Thermal impedance</i> .
11-Feb-2019	5	Updated Section 4 Package information Minor text changes.

Contents

1	Electrical ratings	2
2	Electrical characteristics	3
2.1	Electrical characteristics (curves)	5
3	Test circuit	8
4	Package information	9
4.1	PowerFLAT™ 5x6 WF type R package information	9
4.2	PowerFLAT™ 5x6 WF packing information	13
	Revision history	15
	Contents	16

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